TY Semicondutor[®]



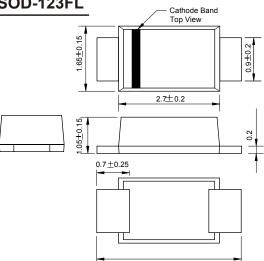
Product specification

MBR120 THRU MBR1100

FEATURES

SOD-123FL

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds,0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension



MECHANICAL DATA

Case: JEDEC SOD-123FL molded plastic body Terminals: Solderable per MIL-STD-750, Method 2026 Polarity: Color band denotes cathode end Mounting Position: Any

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	MBRS 120-FL	MBRS 130-FL	MBRS 140-FL	MBRS 150-FL	MBRS 160-FL	MBRS 170-FL	MBRS 180-FL	MBRS 190-FL	MBRS 1100-FL	UNITS
	Marking	D12	D13	D14	D15	D16	D17	D18	D19	D110	
Maximum repetitive peak reverse voltage	Vrrm	20	30	40	50	60	70	80	90	100	VOLTS
Maximum RMS voltage	Vrms	14	21	28	35	42	49	56	63	70	VOLTS
Maximum DC blocking voltage	Vdc	20	30	40	50	60	70	80	90	100	VOLTS
Maximum average forward rectified current	l(AV)	1.0								Amp	
Peak forward surge current											
8.3ms single half sine-wave superimposed on	Ігѕм 25.0								Amps		
rated load (JEDEC Method)											
Maximum instantaneous forward voltage at 1.0A	Vf	0.55			0.	70			0.85		Volts
Maximum DC reverse current Ta=25℃	0.5									~ ^	
at rated DC blocking voltage Ta=100℃	IR	10.0				5.0			mA		
Typical junction capacitance (NOTE 1)	CJ	110				80			30		pF
Operating junction temperature range	ТJ	-65 to +125 -65 to +150					+150	°C			
Storage temperature range	Тѕтс	-65 to +150									°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.